TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

2SC3075

Switching Regulator and High Voltage Switching Applications

DC-DC Converter Applications

DC-AC Converter Applications

• Excellent switching times: $t_r = 1.0 \mu s \text{ (max)}$

 $t_f = 1.5 \mu s \text{ (max)}, (I_C = 0.5 \text{ A})$

• High collector breakdown voltage: $V_{CEO} = 400 \text{ V}$

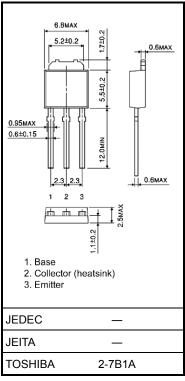
Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	500	V	
Collector-emitter voltage		V _{CEO}	400	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	IC	0.8	Α	
	Pulse	I _{CP}	1.5		
Base current		ΙΒ	0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

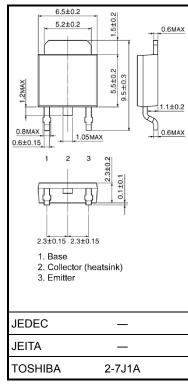
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm



Weight: 0.36 g (typ.)

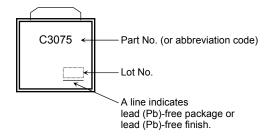


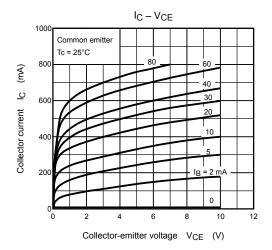
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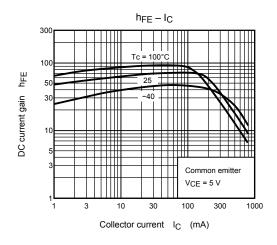
Electrical Characteristics (Ta = 25°C)

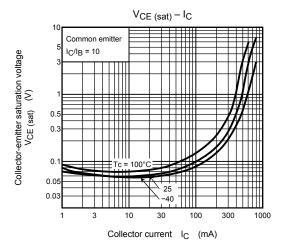
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = 400 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	100	μΑ
Collector-base bre	eakdown voltage	V (BR) CBO	I _C = 1 mA, I _E = 0	500	_	_	V
Collector-emitter I	oreakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	400	_	_	V
DC current gain		h _{FE}	V _{CE} = 5 V, I _C = 0.1 A	20	_	100	
			V _{CE} = 5 V, I _C = 0.5 A	10	_	_	
Collector-emitter	saturation voltage	V _{CE (sat)}	I _C = 0.1 A, I _B = 0.01 A	_	_	0.5	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.1 A, I _B = 0.01 A	_	_	1.0	V
Switching time Stor	Rise on time	t _r	20 µs INPUT → CC ≈ 200 V	_	_	1.0	
	Storage time	t _{stg}		_	_	2.5	μs
	Fall time	t _f	I _{B1} = −I _{B2} = 0.05 A, Duty cycle ≤ 1%	_	_	1.5	

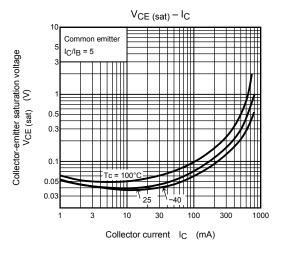
Marking

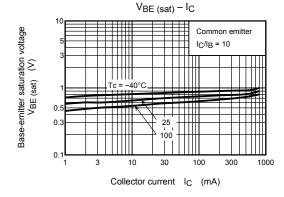


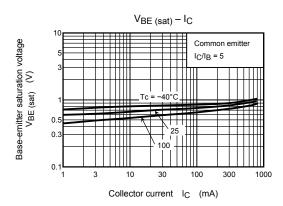




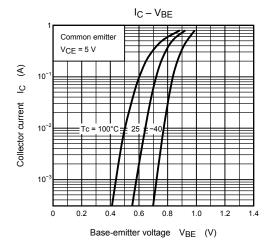


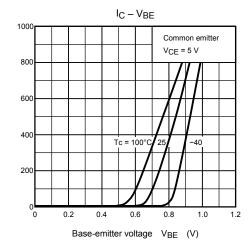






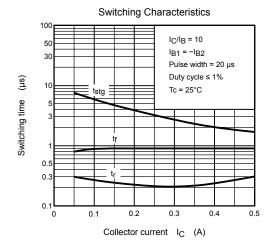
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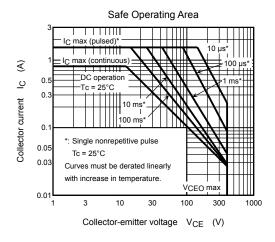


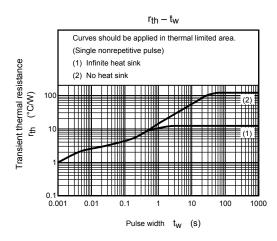


(mA)

Collector current I_C







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20070701-EN

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